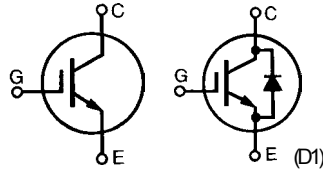


# HiPerFAST™ IGBT

IXGH39N60B  
IXGH39N60BD1  
IXGT39N60B  
IXGT39N60BD1

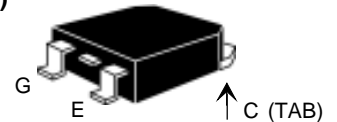
$V_{CES} = 600 \text{ V}$   
 $I_{C25} = 76 \text{ A}$   
 $V_{CE(sat)} = 1.7 \text{ V}$   
 $t_{fi} = 200 \text{ ns}$

Preliminary data

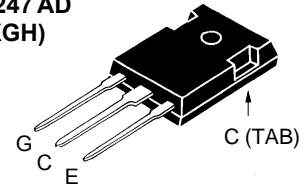


Symbol	Test Conditions	Maximum Ratings	
$V_{CES}$	$T_J = 25^\circ\text{C to } 150^\circ\text{C}$	600	V
$V_{CGR}$	$T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 1 \text{ M}\Omega$	600	V
$V_{GES}$	Continuous	$\pm 20$	V
$V_{GEM}$	Transient	$\pm 30$	V
$I_{C25}$	$T_C = 25^\circ\text{C}$	76	A
$I_{C90}$	$T_C = 90^\circ\text{C}$	39	A
$I_{CM}$	$T_C = 25^\circ\text{C}, 1 \text{ ms}$	152	A
<b>SSOA (RBSOA)</b>	$V_{GE} = 15 \text{ V}, T_{VJ} = 125^\circ\text{C}, R_G = 22 \Omega$ Clamped inductive load	$I_{CM} = 76$ @ $0.8 V_{CES}$	A
$P_C$	$T_C = 25^\circ\text{C}$	200	W
$T_J$		-55 ... +150	$^\circ\text{C}$
$T_{JM}$		150	$^\circ\text{C}$
$T_{stg}$		-55 ... +150	$^\circ\text{C}$
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300	$^\circ\text{C}$
$M_d$	Mounting torque (M3) TO-247	1.13/10Nm/lb.in.	
<b>Weight</b>		TO-247 AD	6 g
		TO-268	4 g

TO-268 (IXGT)



TO-247 AD (IXGH)



G = Gate, C = Collector,  
E = Emitter, TAB = Collector

## Features

- International standard packages JEDEC TO-247 AD & TO-268
- High current handling capability
- Newest generation HDMOS™ process
- MOS Gate turn-on - drive simplicity

## Applications

- PFC circuits
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies

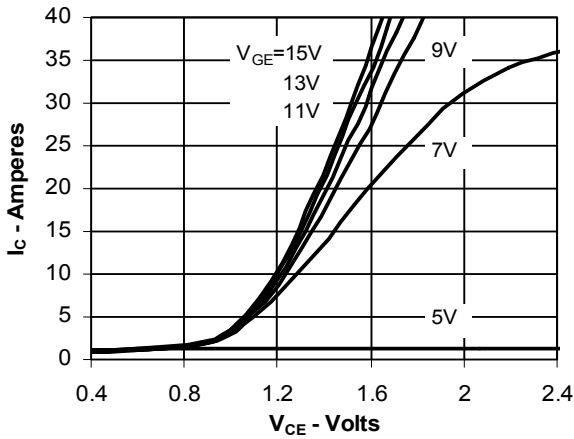
## Advantages

- High power density
- Very fast switching speeds for high frequency applications

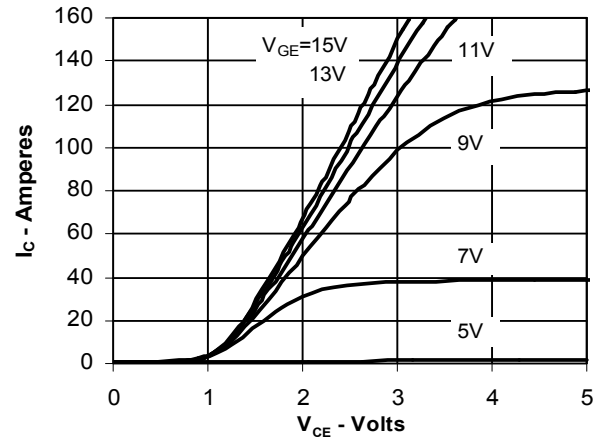
Symbol	Test Conditions		Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
			Min.	Typ.	Max.
$BV_{CES}$	$I_C = 250 \mu\text{A}, V_{GE} = 0 \text{ V}$	39N60B	600		V
		39N60BD1	600		
$V_{GE(th)}$	$I_C = 250 \mu\text{A}, V_{CE} = V_{GE}$	39N60B	2.5		5.0 V
		39N60BD1	2.5		5.0 V
$I_{CES}$	$V_{CE} = 0.8 \cdot V_{CES}, V_{GE} = 0 \text{ V}$	$T_J = 25^\circ\text{C}$ 39N60B			200 $\mu\text{A}$
		$T_J = 125^\circ\text{C}$ 39N60B			1 mA
		$T_J = 125^\circ\text{C}$ 39N60BD1			3 mA
$I_{GES}$	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$				$\pm 100 \text{ nA}$
$V_{CE(sat)}$	$I_C = I_{90}, V_{GE} = 15 \text{ V}$				1.7 V



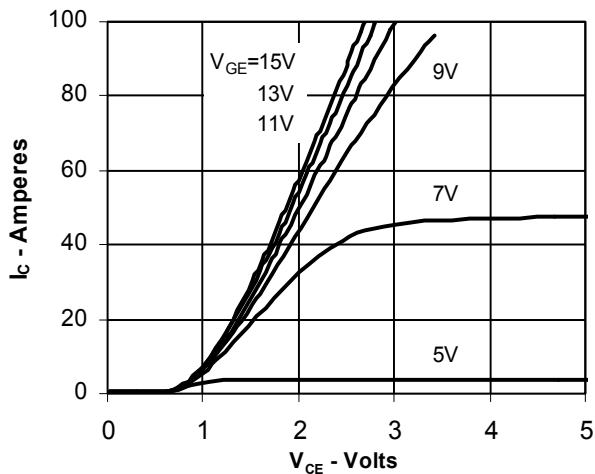
**Fig. 1. Saturation Voltage Characteristics @ 25 Deg. C**



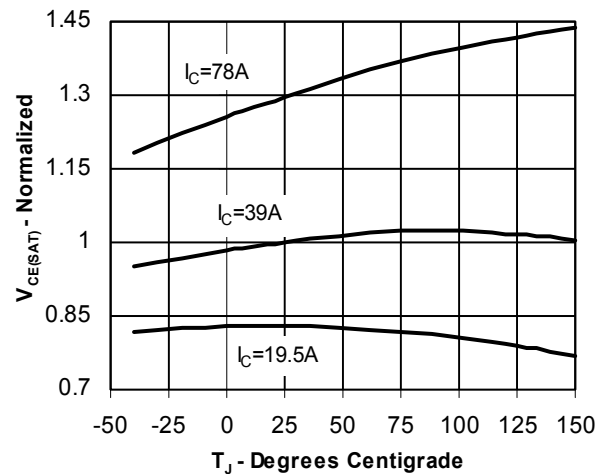
**Fig. 2. Extended Output Characteristics @ 25 Deg. C**



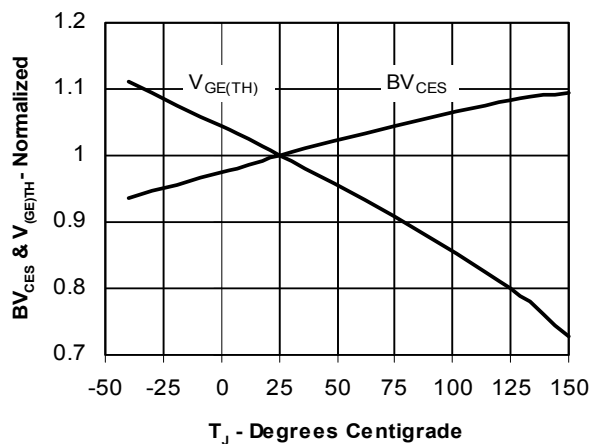
**Fig. 3. Saturation Voltage Characteristics @ 125 Deg. C**



**Fig. 4. Temperature Dependence of  $V_{CE(SAT)}$**



**Fig. 5.  $BV_{CES}$  &  $V_{(GE)TH}$  vs. Junction Temperature**



**Fig. 6. Admittance**

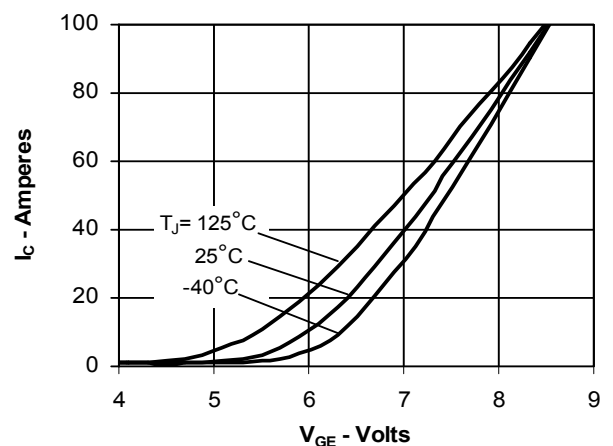


Fig. 7. Transconductance

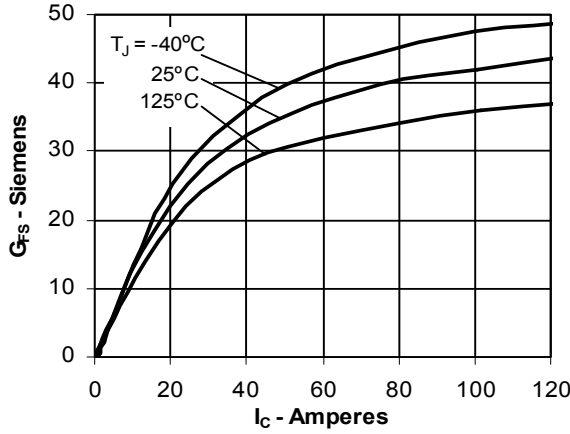


Fig. 8. Dependence of  $E_{OFF}$  on  $I_c$

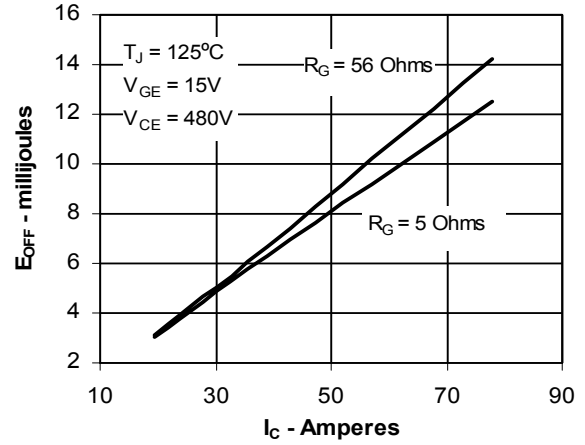


Fig. 9. Dependence of  $E_{OFF}$  on  $R_G$

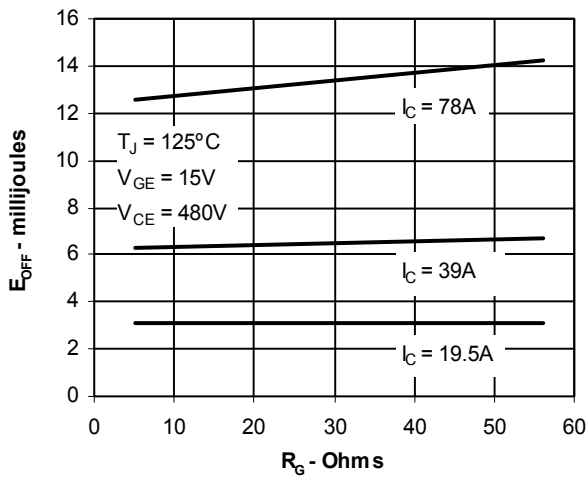


Fig. 10. Dependence of  $E_{OFF}$  on Temperature

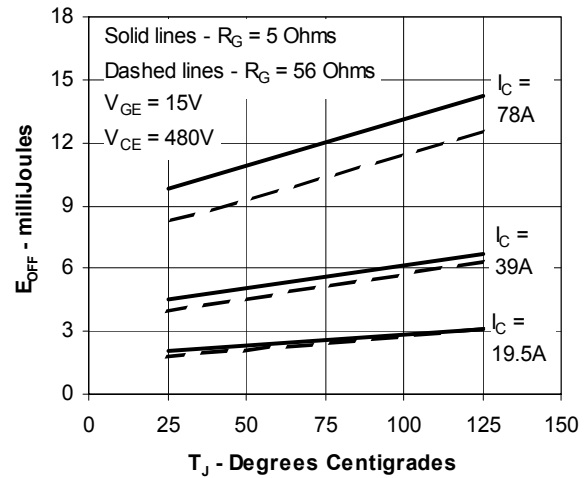


Fig. 11. Gate Charge

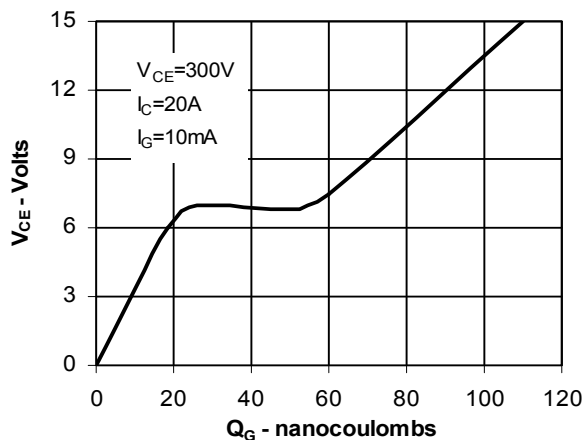
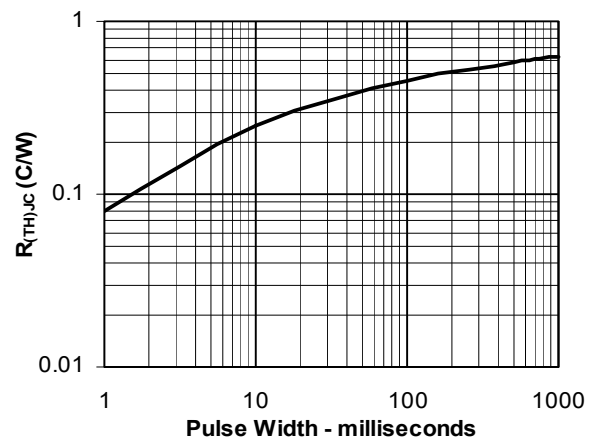


Fig. 12. Transient Thermal Response



IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETS and IGBTs are covered by one or more of the following U.S. patents:

4,835,592	4,881,106	5,017,508	5,049,961	5,187,117	5,486,715	6,306,728B1
4,850,072	4,931,844	5,034,796	5,063,307	5,237,481	5,381,025	

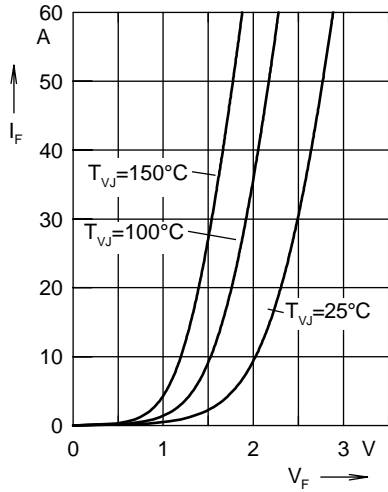


Fig. 12 Forward current  $I_F$  versus  $V_F$

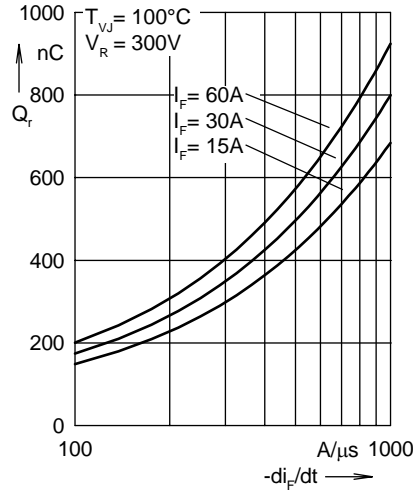


Fig. 13 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

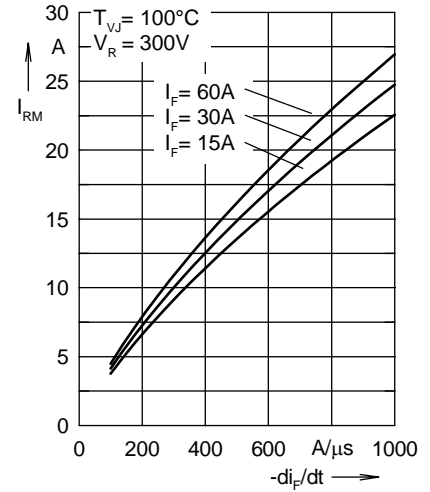


Fig. 14 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

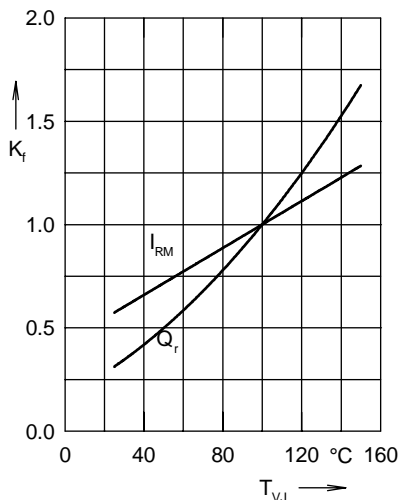


Fig. 15 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

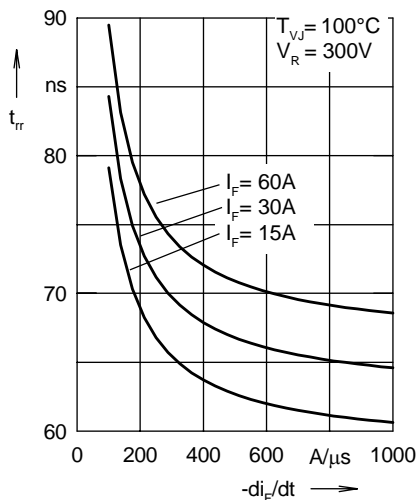


Fig. 16 Recovery time  $t_{rr}$  versus  $-di_F/dt$

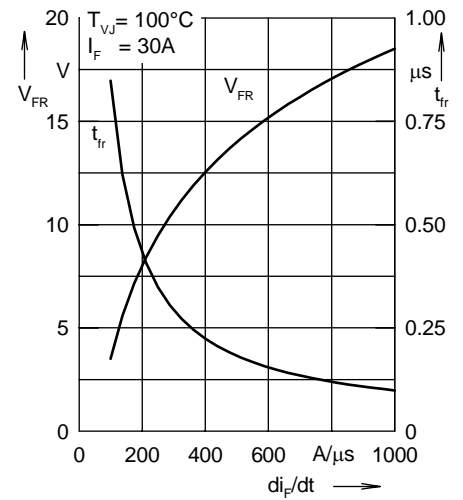


Fig. 17 Peak forward voltage  $V_{FR}$  and  $t_{rr}$  versus  $di_F/dt$

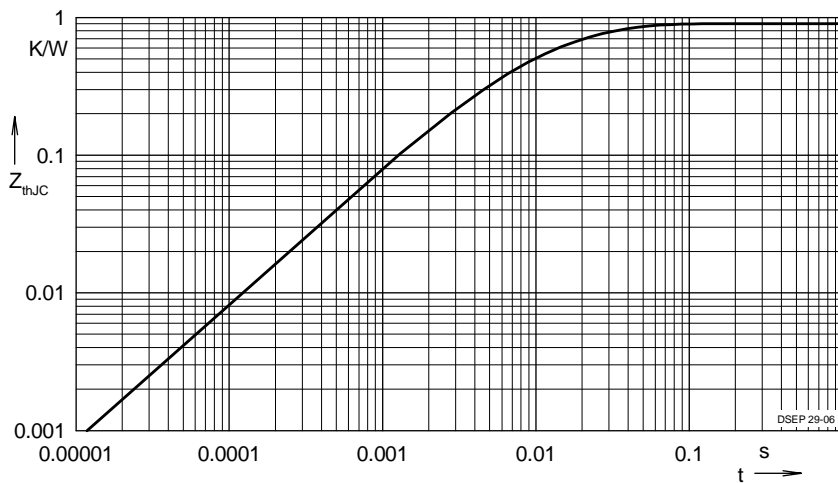


Fig. 18 Transient thermal resistance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.502	0.0052
2	0.193	0.0003
3	0.205	0.0162